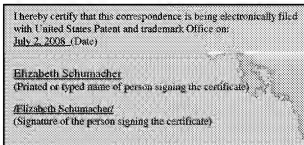


IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Wen Lin, *et al.*
Serial No.: 10/814,682
Filed: March 31, 2004
Title: SEMICONDUCTOR DEVICE HAVING A DOPED LATTICE
MATCHING LAYER AND A METHOD OF MANUFACTURE
THEREFOR
Grp./A.U.: 2823
Examiner: Julio J. Maldonado Confirmation No.: 8308

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450



Sir:

REQUEST FOR RECONSIDERATION UNDER 37 C.F.R. § 1.111

In response to the Examiner's Action mailed May 2, 2008, please reconsider the above-identified application for the following reasons: